



15-W Filter-Free Stereo Class-D Audio Power Amplifier with SpeakerGuard™

Check for Samples: TPA3117D2

FEATURES

- 15-W/ch into 8Ω Loads at 10% THD+N From a 16V Supply
- 10-W/ch into 8Ω Loads at 10% THD+N From a 13V Supply
- 90% Efficient Class-D Operation Eliminates **Need for Heat Sinks**
- Wide Supply Voltage Range Allows Operation from 8V to 26V
- **Filter-Free Operation**
- SpeakerGuard™ Speaker Protection Includes Adjustable Power Limiter
- Excellent THD+N / Pop-Free Performance
- Four Selectable, Fixed Gain Settings
- **Differential Inputs**
- Selectable Switching Frequency (290kHz or 390kHz) Allows Multiple Devices to be Used in **One System**
- Integrated 5V Regulator With up to 30 mA of **Output Current for Powering External Data** Converters
- 5mm x 5mm QFN Packaging

APPLICATIONS

- **Televisions**
- **Consumer Audio Equipment**
- **All-in-One Computers**

DESCRIPTION

The TPA3117D2 is a 15W (per channel) efficient, Class-D audio power amplifier for driving bridged-tied speakers. Advanced EMI Suppression Technology enables the use of inexpensive ferrite bead filters at the outputs while meeting EMC requirements. SpeakerGuard™ speaker protection circuitry includes an adjustable power limiter. The adjustable power limiter allows the user to set a "virtual" voltage rail lower than the chip supply to limit the amount of current through the speaker.

The TPA3117D2 can drive stereo speakers as low as 4Ω . The high efficiency of the TPA3117D2, 90%, eliminates the need for an external heat sink when playing music.

The outputs are also fully protected against shorts to GND, V_{CC}, and output-to-output. The short-circuit protection and thermal protection includes an auto-recovery feature.

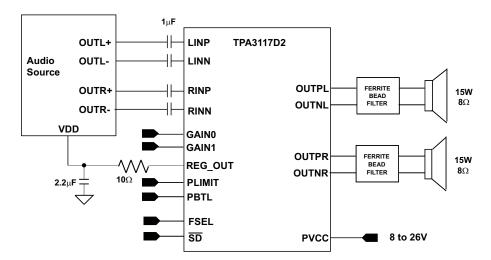


Figure 1. TPA3117D2 Simplified Application Schematic

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. SpeakerGuard is a trademark of Texas Instruments.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

| | | | UNIT | | |
|------------------|---|--|---------------------------------|--|--|
| V _{CC} | Supply voltage | AVCC, PVCC | -0.3V to 30V | | |
| | | SD, GAIN0, GAIN1, PBTL, FSEL ⁽²⁾ | -0.3V to V _{CC} + 0.3V | | |
| V_{I} | Interface pin voltage | PLIMIT | -0.3V to REG_OUT + 0.3V | | |
| | | RINN, RINP, LINN, LINP | -0.3V to 6.3V | | |
| | Continuous total power dissi | pation | See Dissipation Rating Table | | |
| T _A | Operating free-air temperatu | ire range | -40°C to 85°C | | |
| TJ | Operating junction temperature range ⁽³⁾ | | -40°C to 150°C | | |
| T _{stg} | Storage temperature range | | −65°C to 150°C | | |
| | | BTL: PVCC > 15V | 4.8 | | |
| R_L | Minimum Load Resistance | BTL: PVCC ≤ 15V | 3.2 | | |
| | | PBTL | 3.2 | | |
| F0D | Flactor de Carlon de anno | Human body model (4) (all pins) | ±2kV | | |
| ESD | Electrostatic discharge | Charged-device model ⁽⁵⁾ (all pins) | ±500V | | |

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operations of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) For input voltage >6V, a series current limiting resistor of at least 100kΩ is recommended.

- (4) In accordance with JEDEC Standard 22, Test Method A114-B.
- (5) In accordance with JEDEC Standard 22, Test Method C101-A

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | MAX | UNIT |
|-----------------|--------------------------------|--|-----|-----|------|
| V_{CC} | Supply voltage | PVCC, AVCC | 8 | 26 | V |
| V_{IH} | High-level input voltage | SD, GAIN0, GAIN1, PBTL, FSEL | 2 | | V |
| V _{IL} | Low-level input voltage | SD, GAINO, GAIN1, PBTL, FSEL | | 0.8 | V |
| I _{IH} | High-level input current | SD, GAINO, GAIN1, PBTL, FSEL, V _I = 2V, V _{CC} = 18V | | 50 | μΑ |
| I _{IL} | Low-level input current | SD, GAINO, GAIN1, PBTL, FSEL, V _I = 0.8V, V _{CC} = 18V | | 5 | μΑ |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

THERMAL INFORMATION

| | THERMAL METRIC ⁽¹⁾ | TPA3117D2 | LINUTO | |
|-------------------------|--|---------------|--------|--|
| | THERMAL METRIC** | RHB (32 PINS) | UNITS | |
| θ_{JA} | Junction-to-ambient thermal resistance | 33.7 | | |
| $\theta_{JC(top)}$ | Junction-to-case(top) thermal resistance | 36.3 | | |
| $\theta_{\sf JB}$ | Junction-to-board thermal resistance | 9.8 | °C/\/ | |
| ΨЈТ | Junction-to-top characterization parameter | 0.6 | °C/W | |
| ΨЈВ | Junction-to-board characterization parameter | 9.5 | | |
| θ _{JC(bottom)} | Junction-to-case(bottom) thermal resistance | 3.2 | | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

⁽³⁾ The TPA3117D2 incorporates an exposed thermal pad on the underside of the chip. This acts as a heatsink, and it must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in the device going into thermal protection shutdown.



DC CHARACTERISTICS

 $T_A = 25$ °C, $V_{CC} = 24$ V, $R_L = 8$ Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITION | MIN | TYP | MAX | UNIT | | |
|---------------------|---|---|---------------|------|------|------|-----|--|
| Vos | Class-D output offset voltage (measured differentially) | V _I = 0V, Gain = 18.2dB | | | 1.5 | 15 | mV | |
| I _{CC} | Quiescent supply current | \overline{SD} = 2V, no load, V_{CC} = 26V | | | 25 | 50 | mA | |
| I _{CC(SD)} | Quiescent supply current in shutdown mode | \overline{SD} = 0.8V, no load, V_{CC} = 24V | | | 2.5 | 5 | mA | |
| _ | Duning any united and interest | $V_{CC} = 12V, I_{O} = 500mA,$ | High Side | | 240 | | 0 | |
| r _{DS(on)} | Drain-source on-state resistance | $T_J = 25^{\circ}C$ | Low side | | 240 | | mΩ | |
| | | CAINIA O OV | GAIN0 = 0.8 V | 8 | 9 | 10 | -10 | |
| 0 | Caia | GAIN1 = 0.8V | GAIN0 = 2 V | 11.1 | 12.1 | 13.1 | dB | |
| G | Gain | CAINIA | GAIN0 = 0.8 V | 14.2 | 15.2 | 16.2 | -10 | |
| | | GAIN1 = 2V | GAIN0 = 2 V | 17.2 | 18.2 | 19.2 | dB | |
| t _{on} | Turn-on time | SD = 2V | | | 14 | | ms | |
| t _{OFF} | Turn-off time | SD = 0.8V | | | 2 | | μS | |

DC CHARACTERISTICS

 $T_A = 25$ °C, $V_{CC} = 12$ V, $R_L = 8$ Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITION | MIN | TYP | MAX | UNIT | |
|---------------------|---|---|---------------|------|------|------|----|
| Vos | Class-D output offset voltage (measured differentially) | V _I = 0V, Gain = 18.2dB | | | 1.5 | 15 | mV |
| I _{CC} | Quiescent supply current | \overline{SD} = 2V, no load, V_{CC} = 12V | | | 15 | 35 | mA |
| I _{CC(SD)} | Quiescent supply current in shutdown mode | \overline{SD} = 0.8V, no load, V_{CC} = 12V | | | 2.5 | 5 | mA |
| r _{DS(on)} | Dunin course on etata accietance | $V_{CC} = 12V, I_{O} = 500mA,$ | High Side | | 240 | | 0 |
| | Drain-source on-state resistance | T _J = 25°C | Low side | | 240 | | mΩ |
| | | CAINIA O OV | GAIN0 = 0.8 V | 8 | 9 | 10 | dB |
| 0 | Cain | GAIN1 = 0.8V | GAIN0 = 2 V | 11.1 | 12.1 | 13.1 | |
| G | Gain | CAINIA OV | GAIN0 = 0.8 V | 14.2 | 15.2 | 16.2 | ٩D |
| | | GAIN1 = 2V | GAIN0 = 2 V | 17.2 | 18.2 | 19.2 | dB |
| t _{ON} | Turn-on time | SD = 2V | | | 14 | | ms |
| t _{OFF} | Turn-off time | SD = 0.8V | | | 2 | | μS |

LDO CHARACTERISTICS

 $T_A = 25$ °C, $V_{CC} = 12$ V (unless otherwise noted)

| PARAMETER | | TEST CONI | TEST CONDITIONS | | | MAX | UNIT |
|-----------|-----------------------------------|--|-----------------|----|------|-----|---------|
| VI | Input voltage | V _{CC} | | 8 | 12 | 26 | V |
| Io | Continuous output current | | | | | 30 | mA |
| Vo | Output voltage | 0 < I _O < 30mA, 10.8V < V _{IN} < | | 5 | | V | |
| | Line regulation | I _L = 5mA, 10.8V < V _{IN} < 13.2V | | | 6 | | μV |
| | Load regulation | I_L = 0 - 30mA, V_{IN} = 12V, Measurement taken with an external 10Ω series resistor | | | 10.2 | | mV / mA |
| DCDD | Davis a supeli signal a vaigation | \/ 40\/ L 20m A | f = 100Hz | | 92 | | -10 |
| PSRR | Power supply ripple rejection | $V_{CC} = 12V$, $I_L = 20mA$ | f = 1kHz | 72 | | | dB |

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TEXAS INSTRUMENTS

AC CHARACTERISTICS

 $T_A = 25$ °C, $V_{CC} = 24$ V, $R_L = 8$ Ω (unless otherwise noted)

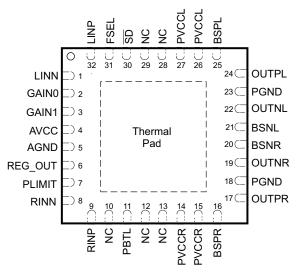
| PARAMETER | | TEST CONDITIONS | MIN TYP MAX | UNIT |
|------------------|-----------------------------------|---|-------------|-------|
| K _{SVR} | Power Supply ripple rejection | 200mV _{PP} ripple at 1kHz, Gain = 18.2dB, Inputs ac-coupled to AGND | -70 | dB |
| Po | Continuous output power | THD+N = 10%, f = 1kHz, V _{CC} = 16V | 15 | W |
| THD+N | Total harmonic distortion + noise | $V_{CC} = 16V$, $f = 1kHz$, $P_O = 7.5W$ (half-power) | 0.1 | % |
| | Output into material acies | 2011- to 20111- A weighted filter Coin AdD | 55 | μV |
| V_n | Output integrated noise | 20Hz to 22kHz, A-weighted filter, Gain = 9dB | -85 | dBV |
| | Crosstalk | V _O = 1Vrms, Gain = 9dB, f = 1kHz | -100 | dB |
| SNR | Signal-to-noise ratio | Maximum output at THD+N < 1%, f = 1kHz, Gain = 9dB, A-weighted | 102 | dB |
| ı | Ossillator fraguency | FSEL = 0.8V | 290 | ld la |
| fosc | Oscillator frequency | FSEL = 2V | 390 | kHz |
| | Thermal trip point | | 150 | °C |
| | Thermal hysteresis | | 15 | °C |

AC CHARACTERISTICS

 T_A = 25°C, V_{CC} = 12 V, R_L = 8 Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN TYP | MAX | UNIT |
|------------------|-----------------------------------|--|---------|-----|------|
| K _{SVR} | Supply ripple rejection | 200mV _{PP} ripple from 20Hz – 1kHz, Gain = 18.2dB, Inputs ac-coupled to AGND | -70 | | dB |
| Po | Continuous output power | THD+N = 10%, f = 1kHz; V _{CC} = 13V | 10 | | W |
| THD+N | Total harmonic distortion + noise | $R_L = 8\Omega$, $f = 1kHz$, $P_O = 5W$ (half-power) | 0.06 | | % |
| V _n | Output into another a single | COLLE LE COLLE A suscialité d'Élèce Colle Colle | 48 | | μV |
| | Output integrated noise | 20Hz to 22kHz, A-weighted filter, Gain = 9dB | -86 | | dBV |
| | Crosstalk | P _o = 1W, Gain = 9dB, f = 1kHz | -100 | | dB |
| SNR | Signal-to-noise ratio | Maximum output at THD+N < 1%, f = 1kHz, Gain = 9dB, A-weighted | 102 | | dB |
| , | One'lleter frames | FSEL = 0.8V | 290 | | |
| fosc | Oscillator frequency | FSEL = 2V | 390 | | kHz |
| | Thermal trip point | | 150 | | °C |
| | Thermal hysteresis | | 15 | | °C |

RHB (QFN) PACKAGE (TOP VIEW)



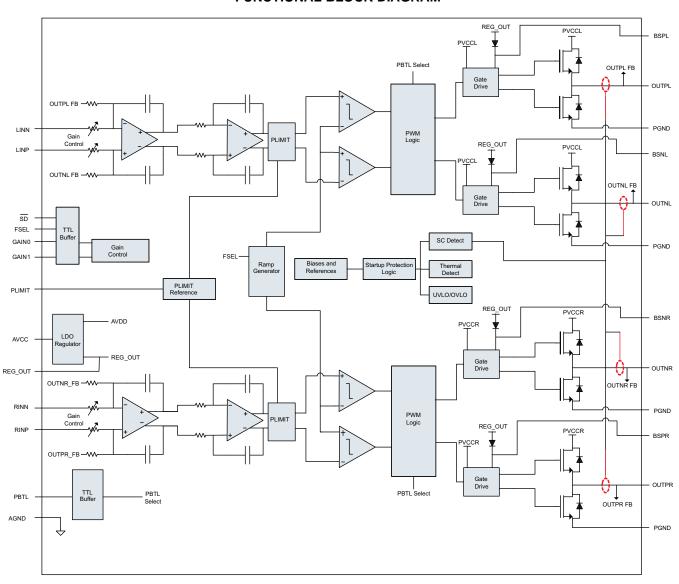


PIN FUNCTIONS

| PIN | | | |
|-------------|-----------------------|-------|--|
| NAME NUMBER | | I/O/P | DESCRIPTION |
| LINN | 1 | - 1 | Negative audio input for left channel. Biased at 3V. |
| GAIN0 | 2 | I | Gain select least significant bit. TTL logic levels with compliance to AVCC. |
| GAIN1 | 3 | I | Gain select most significant bit. TTL logic levels with compliance to AVCC. |
| AVCC | 4 | Р | Analog supply |
| AGND | 5 | | Analog signal ground. Connect to the thermal pad. |
| REG_OUT | 6 | 0 | 5V regulated output. Connect 2.2 μ F to AGND after the series 10 Ω resistor. |
| PLIMIT | 7 | I | Power limit level adjust. Connect a resistor divider from REG_OUT to AGND to set power limit. Connect directly to REG_OUT for no power limit. |
| RINN | 8 | - 1 | Negative audio input for right channel. Biased at 3V. |
| RINP | 9 | I | Positive audio input for right channel. Biased at 3V. |
| NC | 10, 12, 13, 28, 29 | | Not connected |
| PBTL | 11 | I | Parallel BTL mode switch (low = BTL mode, high = PBTL mode) |
| PVCCR | 14, 15 | Р | Power supply for right channel H-bridge. Right channel and left channel power supply inputs are connected internally. PVCCR and PVCCL must be connected together on the PCB. |
| BSPR | 16 | I | Bootstrap I/O for right channel, positive high-side FET. |
| OUTPR | 17 | 0 | Class-D H-bridge positive output for right channel. |
| PGND | 18 | | Power ground for the H-bridges. |
| OUTNR | 19 | 0 | Class-D H-bridge negative output for right channel. |
| BSNR | 20 | I | Bootstrap I/O for right channel, negative high-side FET. |
| BSNL | 21 | I | Bootstrap I/O for left channel, negative high-side FET. |
| OUTNL | 22 | 0 | Class-D H-bridge negative output for left channel. |
| PGND | 23 | | Power ground for the H-bridges. |
| OUTPL | 24 | 0 | Class-D H-bridge positive output for left channel. |
| BSPL | 25 | I | Bootstrap I/O for left channel, positive high-side FET. |
| PVCCL | 26, 27 | Р | Power supply for left channel H-bridge. Right channel and left channel power supply inputs are connected internally. PVCCR and PVCCL must be connected together on the PCB. |
| SD | 30 | I | Shutdown logic input for audio amp (LOW = outputs Hi-Z, HIGH = outputs enabled). TTL logic levels with compliance to AVCC. |
| FSEL | 31 | I | Frequency select input pin (low = 300kHz, high = 400kHz) |
| LINP | 32 | I | Positive audio input for left channel. Biased at 3V. |



FUNCTIONAL BLOCK DIAGRAM

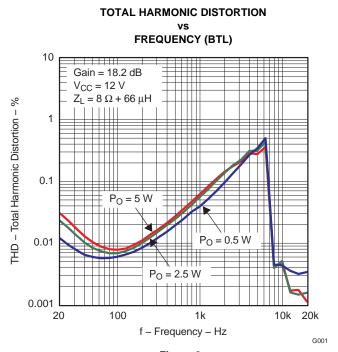


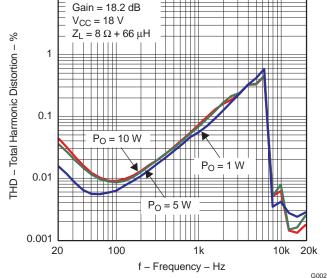


TYPICAL CHARACTERISTICS

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)

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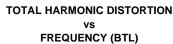


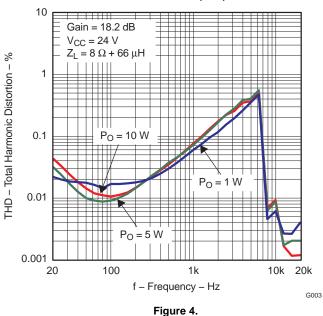


TOTAL HARMONIC DISTORTION

FREQUENCY (BTL)

Figure 2.





TOTAL HARMONIC DISTORTION vs

Figure 3.

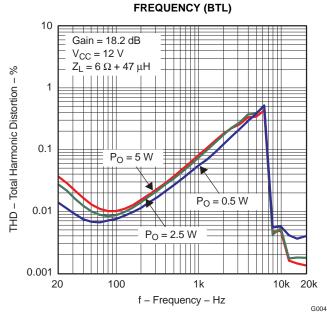
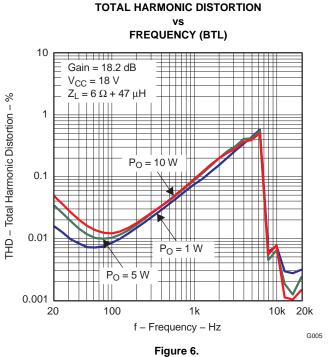


Figure 5.

TEXAS INSTRUMENTS

TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)



TOTAL HARMONIC DISTORTION
vs
FREQUENCY (BTL)

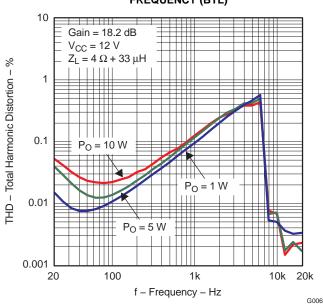
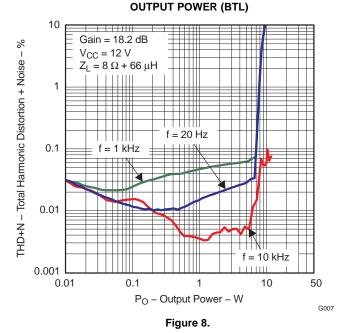


Figure 7.

TOTAL HARMONIC DISTORTION + NOISE



TOTAL HARMONIC DISTORTION + NOISE
vs
OUTPUT POWER (BTL)

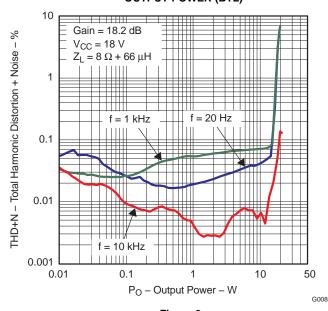


Figure 9.

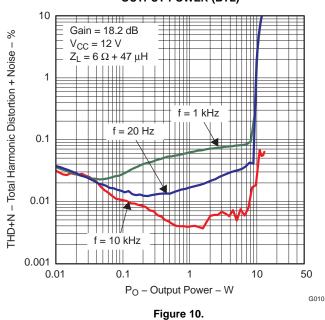


TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)

TOTAL HARMONIC DISTORTION + NOISE

OUTPUT POWER (BTL)



TOTAL HARMONIC DISTORTION + NOISE OUTPUT POWER (BTL)

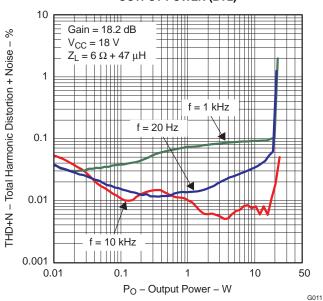
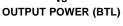


Figure 11.

TOTAL HARMONIC DISTORTION + NOISE vs



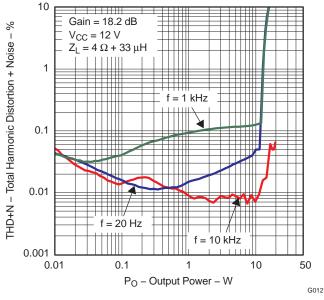


Figure 12.

MAXIMUM OUTPUT POWER

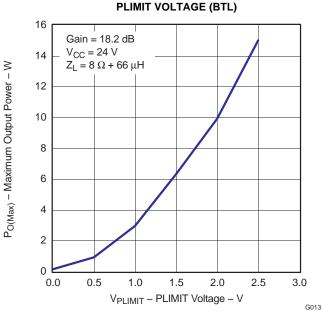
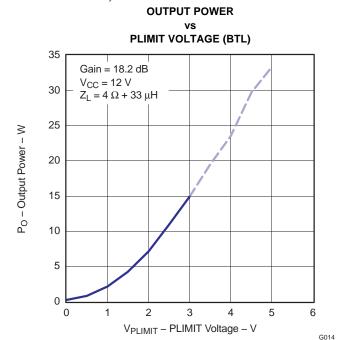


Figure 13.

STRUMENTS

TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)



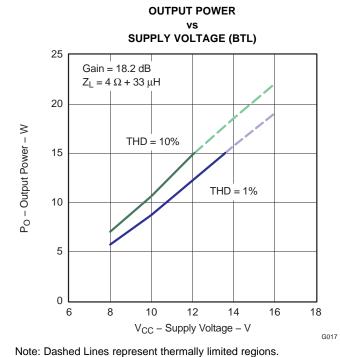
SUPPLY VOLTAGE (BTL) 30 Gain = 18.2 dB $Z_L = 8 \Omega + 66 \mu H$ 25 Po - Output Power - W 20 THD = 10% 15 THD = 1% 10 5 8 10 26 12 14 16 20 22 24 6 18 V_{CC} - Supply Voltage - V G016

OUTPUT POWER

Note: Dashed Lines represent thermally limited regions.

Figure 14.

Note: Dashed Lines represent thermally limited regions. Figure 15.



EFFICIENCY OUTPUT POWER (BTL)

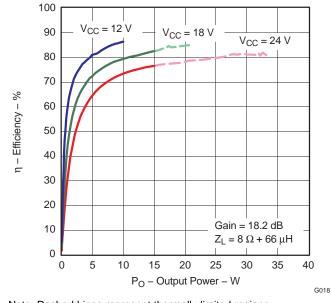


Figure 16.

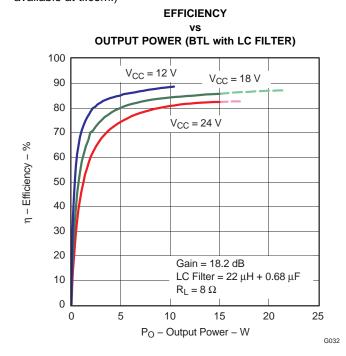
Note: Dashed Lines represent thermally limited regions.

Figure 17.



TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)



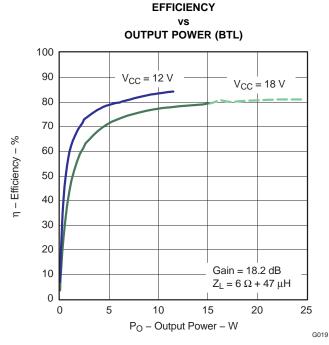
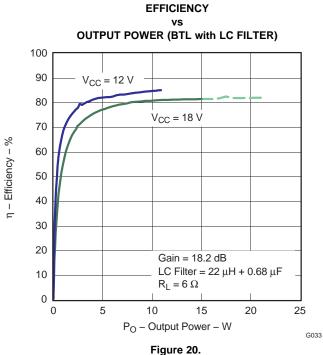


Figure 18.

Note: Dashed Lines represent thermally limited regions. Figure 19.

EFFICIENCY



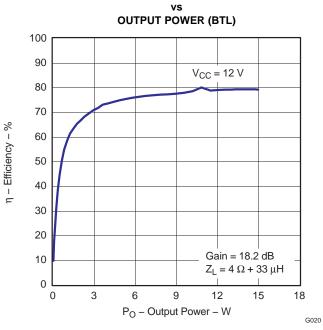
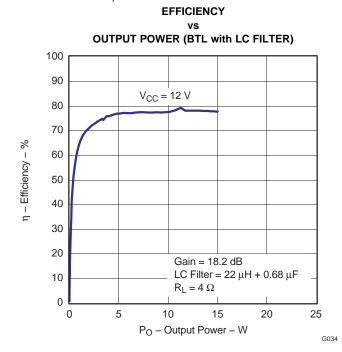


Figure 21.

TEXAS INSTRUMENTS

TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)



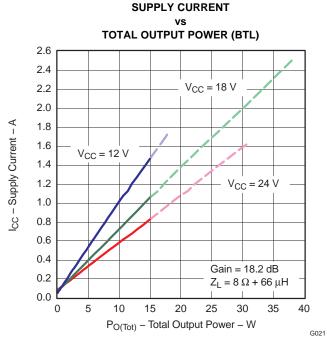
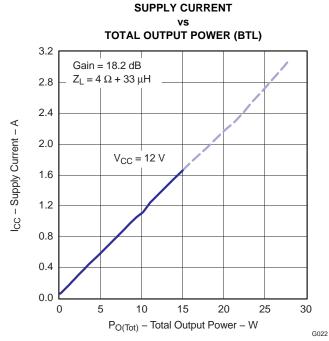


Figure 22.

Note: Dashed Lines represent thermally limited regions.

Figure 23.

CROSSTALK



Note: Dashed Lines represent thermally limited regions. Figure 24.

FREQUENCY (BTL) -20 Gain = 18.2 dB -30 $V_{CC} = 12 V$ $V_0 = 1 \text{ Vrms}$ -40 $Z_L = 8 \Omega + 66 \mu H$ -50 -60 Crosstalk – dB -70 -80 Right to Left -90 -100 Left to Right -110-120-130100 10k 20 1k f - Frequency - Hz

Figure 25.

Submit Documentation Feedback

20k

G023



TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)

SUPPLY RIPPLE REJECTION RATIO

FREQUENCY (BTL)

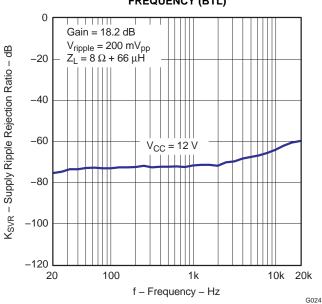


Figure 26.

TOTAL HARMONIC DISTORTION + NOISE

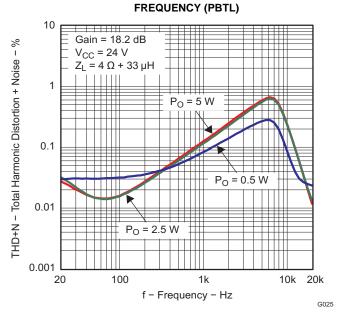


Figure 27.

TOTAL HARMONIC DISTORTION + NOISE

OUTPUT POWER (PBTL)

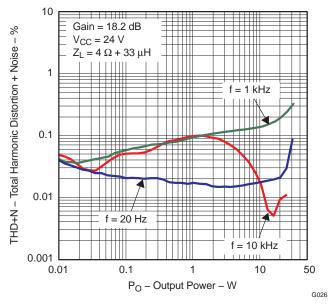
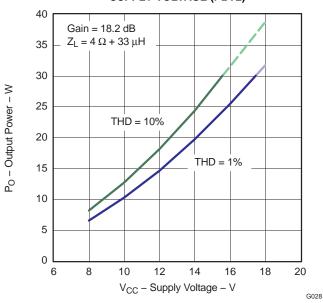


Figure 28.

OUTPUT POWER SUPPLY VOLTAGE (PBTL)



Note: Dashed Lines represent thermally limited regions.

Figure 29.

NSTRUMENTS

TYPICAL CHARACTERISTICS (continued)

(All Measurements taken at 1 kHz, unless otherwise noted. Measurements were made using the TPA3117D2 EVM which is available at ti.com.)

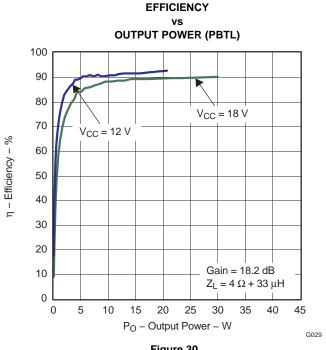


Figure 30.

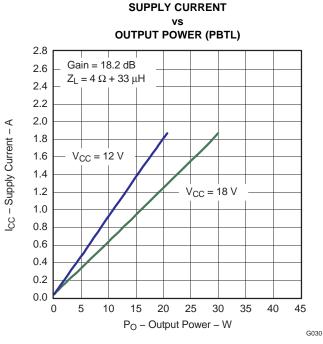


Figure 31.

SUPPLY RIPPLE REJECTION RATIO

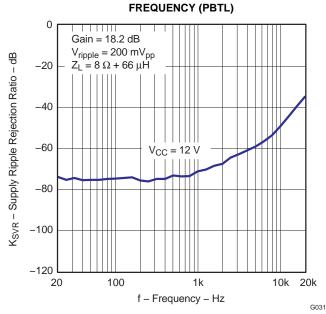


Figure 32.

SUPPLY RIPPLE REJECTION RATIO FREQUENCY (REG_OUT)

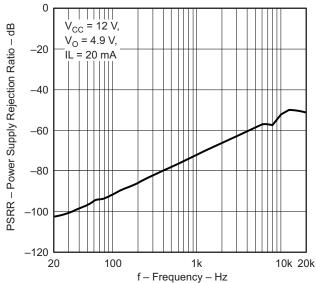


Figure 33.



DEVICE INFORMATION

Gain setting via GAIN0 and GAIN1 inputs

The gain of the TPA3117D2 is set by two input terminals, GAIN0 and GAIN1.

The gains listed in Table 1 are realized by changing the taps on the input resistors inside the amplifier. This causes the input impedance (Z_i) to be dependent on the gain setting. The actual gain settings are controlled by ratios of resistors, so the gain variation from part-to-part is small. However, the input impedance from part-to-part at the same gain may shift by ±20% due to shifts in the actual resistance of the input resistors.

For design purposes, the input network (discussed in the next section) should be designed assuming an input impedance of 60 k Ω , which is the absolute minimum input impedance of the TPA3117D2. At the lower gain settings, the input impedance could increase as high as 256 k Ω

| | | _ | |
|-------|-------|---------------------|----------------------|
| GAIN1 | GAIN0 | AMPLIFIER GAIN (dB) | INPUT IMPEDANCE (kΩ) |
| | | TYP | TYP |
| 0 | 0 | 9 | 213 |
| 0 | 1 | 12.1 | 149 |
| 1 | 0 | 15.2 | 104 |
| 1 | 1 | 18.2 | 74 |

Table 1. Gain Setting

SD OPERATION

The TPA3117D2 employs a shutdown mode of operation designed to reduce supply current (I_{CC}) to the absolute minimum level during periods of nonuse for power conservation. The SD input terminal should be held high (see specification table for trip point) during normal operation when the amplifier is in use. Pulling SD low causes the outputs to mute and the amplifier to enter a low-current state. Never leave SD unconnected, because amplifier operation would be unpredictable.

For the best power-off pop performance, place the amplifier in the shutdown mode prior to removing the power supply voltage. 5V regulator (REG OUT) is active in the shutdown state.

PLIMIT

The voltage at pin 7 can used to limit the power to levels below that which is possible based on the supply rail. Add a resistor divider from REG OUT to ground to set the voltage at the PLIMIT pin. An external reference may also be used if tighter tolerance is required. Also add a 1µF capacitor from pin 7 to ground.

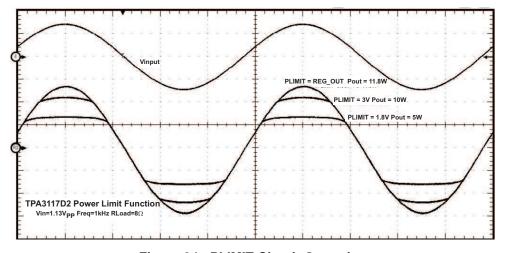


Figure 34. PLIMIT Circuit Operation



The PLIMIT circuit sets a limit on the output peak-to-peak voltage. The limiting is done by limiting the duty cycle to fixed maximum value. This limit can be thought of as a "virtual" voltage rail which is lower than the supply connected to PVCC. This "virtual" rail is 4 times the voltage at the PLIMIT pin. This output voltage can be used to calculate the maximum output power for a given maximum input voltage and speaker impedance.

$$P_{OUT} = \frac{\left(\left(\frac{R_L}{R_L + 2 \times R_S}\right) \times V_P\right)^2}{2 \times R_L}$$
 for unclipped power (1)

Where:

R_S is the total series resistance including R_{DS(on)}, and any resistance in the output filter.

R_I is the load resistance.

V_P is the peak amplitude of the output possible within the supply rail.

 $V_P = 4 \times PLIMIT \text{ voltage if } PLIMIT < 4 \times V_P$

 P_{OUT} (10% THD) = 1.25 × P_{OUT} (unclipped)

REG_OUT Regulator

The TPA3117D2 has an integrated 5V regulator for driving external circuitry. Maximum output current is 30mA. The regulator is always active when power is applied to the device. The \overline{SD} pin does not disable operation. Connect a series 10Ω resister followed by a $2.2\mu F$ capacitor to AGND before routing to the external circuitry. When not used for powering external devices, a series 10Ω resistor with $2.2 \mu F$ of decoupling is still required.

PBTL Select

TPA3117D2 offers the feature of parallel BTL operation with two outputs of each channel connected directly. If the PBTL pin (pin 11) is tied high, the positive and negative outputs of each channel (left and right) are synchronized and in phase. To operate in this PBTL (mono) mode, apply the input signal to the RIGHT input and place the speaker between the LEFT and RIGHT outputs. Connect the positive and negative output together for best efficiency.

For normal BTL operation, connect the PBTL pin to local ground.

SHORT-CIRCUIT PROTECTION

TPA3117D2 has protection from overcurrent conditions caused by a short circuit on the output stage. Amplifier outputs are switched to a Hi-Z state when the short circuit protection latch is engaged. After a typical delay of 250ms, the outputs will resume normal operation until another short occurs. It is not necessary to cycle pin SD to restart the device operation after a short circuit event.

THERMAL PROTECTION

Thermal protection on the TPA3117D2 prevents damage to the device when the internal die temperature exceeds 150°C. There is a ±15°C tolerance on this trip point from device to device. Once the die temperature exceeds the thermal set point, the device enters into the shutdown state and the outputs are disabled. This is not a latched fault. The thermal fault is cleared once the temperature of the die is reduced by 15°C. The device begins normal operation at this point with no external system interaction.

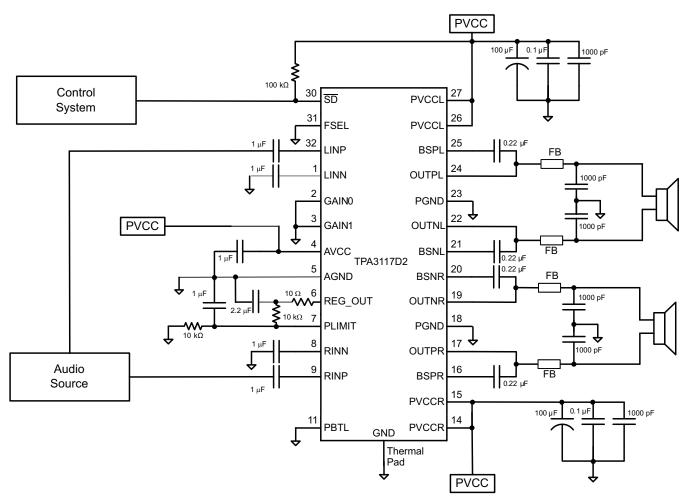
It is not necessary to cycle SD terminal to restart device operation after a short circuit event.

FSEL FUNCTIONALITY

This terminal is used to select the switching frequency of the amplifier. In applications where more than one device is needed, configure one device with FSEL = LOW (290kHz switching) and the other device with FSEL = HIGH (390kHz switching).



APPLICATION INFORMATION



Note: Pins 10, 12, 13, 28 and 29 are NC (not internally connected)

Figure 35. Stereo Class-D Amplifier with BTL Output and Single-Ended Inputs



TPA3117D2 Modulation Scheme

The TPA3117D2 uses a modulation scheme that allows operation without the classic LC reconstruction filter when the amp is driving an inductive load. Each output is switching from 0 volts to the supply voltage. The OUTP and OUTN are in phase with each other with no input so that there is little or no current in the speaker. The duty cycle of OUTP is greater than 50% and OUTN is less than 50% for positive output voltages. The duty cycle of OUTP is less than 50% and OUTN is greater than 50% for negative output voltages. The voltage across the load sits at 0V throughout most of the switching period, reducing the switching current, which reduces any I²R losses in the load.

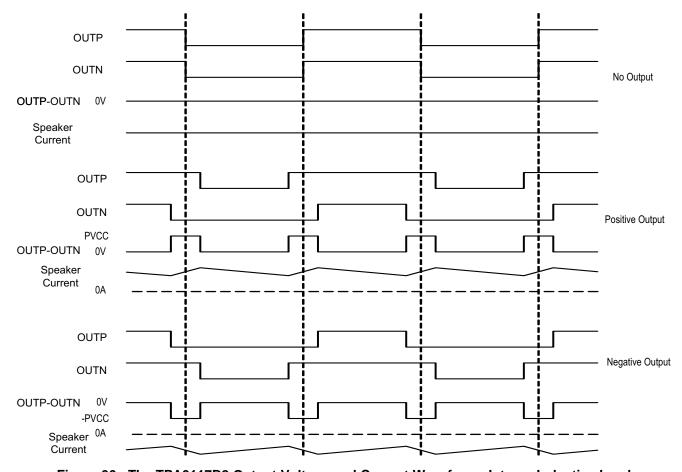


Figure 36. The TPA3117D2 Output Voltage and Current Waveforms Into an Inductive Load

Ferrite Bead Filter Considerations

Using the Advanced Emissions Suppression Technology in the TPA3117D2 amplifier it is possible to design a high efficiency Class-D audio amplifier while minimizing interference to surrounding circuits. It is also possible to accomplish this with only a low-cost ferrite bead filter. In this case it is necessary to carefully select the ferrite bead used in the filter.

One important aspect of the ferrite bead selection is the type of material used in the ferrite bead. Not all ferrite material is alike, so it is important to select a material that is effective in the 10 to 100 MHz range which is key to the operation of the Class D amplifier. Many of the specifications regulating consumer electronics have emissions limits as low as 30 MHz. It is important to use the ferrite bead filter to block radiation in the 30 MHz and above range from appearing on the speaker wires and the power supply lines which are good antennas for these signals. The impedance of the ferrite bead can be used along with a small capacitor with a value in the range of 1000 pF to reduce the frequency spectrum of the signal to an acceptable level. For best performance, the resonant frequency of the ferrite bead/ capacitor filter should be less than 10 MHz.





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Also, it is important that the ferrite bead is large enough to maintain its impedance at the peak currents expected for the amplifier. Some ferrite bead manufacturers specify the bead impedance at a variety of current levels. In this case it is possible to make sure the ferrite bead maintains an adequate amount of impedance at the peak current the amplifier will see. If these specifications are not available, it is also possible to estimate the bead current handling capability by measuring the resonant frequency of the filter output at low power and at maximum power. A change of resonant frequency of less than fifty percent under this condition is desirable. Examples of ferrite beads which have been tested and work well with the TPA3117D2 include 28L0138-80R-10 and HI1812V101R-10 from Steward and the 742792510 from Wurth Electronics.

A high quality ceramic capacitor (x5R or better) is also needed for the ferrite bead filter. A low ESR capacitor with good temperature and voltage characteristics will work best.

Additional EMC improvements may be obtained by adding snubber networks from each of the class D outputs to ground. Suggested values for a simple RC series snubber network would be 10 Ω in series with a 330 pF capacitor although design of the snubber network is specific to every application and must be designed taking into account the parasitic reactance of the printed circuit board as well as the audio amp. Take care to evaluate the stress on the component in the snubber network especially if the amplifer is running at high PVCC. Also, make sure the layout of the snubber network is tight and returns directly to the PGND or the thermal pad beneath the chip.

Efficiency: LC Filter Required With the Traditional Class-D Modulation Scheme

The main reason that the traditional class-D amplifier needs an output filter is that the switching waveform results in maximum current flow. This causes more loss in the load, which causes lower efficiency. The ripple current is large for the traditional modulation scheme, because the ripple current is proportional to voltage multiplied by the time at that voltage. The differential voltage swing is $2 \times V_{CC}$, and the time at each voltage is half the period for the traditional modulation scheme. An ideal LC filter is needed to store the ripple current from each half cycle for the next half cycle, while any resistance causes power dissipation. The speaker is both resistive and reactive, whereas an LC filter is almost purely reactive.

The TPA3117D2 modulation scheme has little loss in the load without a filter because the pulses are short and the change in voltage is V_{CC} instead of 2 × V_{CC} . As the output power increases, the pulses widen, making the ripple current larger. Ripple current could be filtered with an LC filter for increased efficiency, but for most applications the filter is not needed.

An LC filter with a cutoff frequency less than the class-D switching frequency allows the switching current to flow through the filter instead of the load. The filter has less resistance but higher impedance at the switching frequency than the speaker, which results in less power dissipation, therefore increasing efficiency.

When to Use an Output Filter for EMI Suppression

The TPA3117D2 has been tested with a simple ferrite bead filter for a variety of applications including long speaker wires up to 125 cm and high power. The TPA3117D2 EVM passes FCC Class B specifications under these conditions using twisted speaker wires. The size and type of ferrite bead can be selected to meet application requirements. Also, the filter capacitor can be increased if necessary with some impact on efficiency.

There may be a few circuit instances where it is necessary to add a complete LC reconstruction filter. These circumstances might occur if there are nearby circuits which are sensitive to noise. In these cases a classic second order Butterworth filter similar to those shown in the figures below can be used.

Some systems have little power supply decoupling from the AC line but are also subject to line conducted interference (LCI) regulations. These include systems powered by "wall warts" and "power bricks." In these cases, an LC reconstruction filter can be the lowest cost means to pass LCI tests. Common mode chokes using low frequency ferrite material can also be effective at preventing line conducted interference.

Product Folder Link(s): TPA3117D2

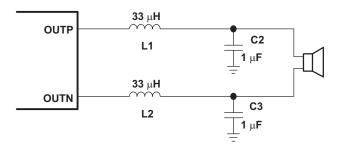


Figure 37. Typical LC Output Filter, Cutoff Frequency of 27 kHz, Speaker Impedance = 8Ω

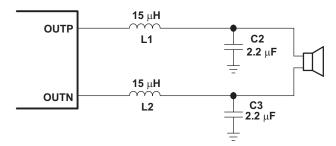


Figure 38. Typical LC Output Filter, Cutoff Frequency of 27 kHz, Speaker Impedance = 4Ω

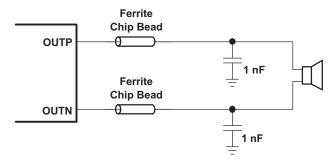
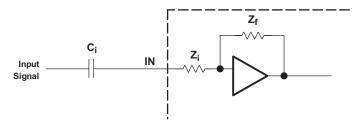


Figure 39. Typical Ferrite Chip Bead Filter (Chip Bead Example:)



INPUT RESISTANCE

Changing the gain setting can vary the input resistance of the amplifier from its smallest value, ±20%, to the largest value, ±20%. As a result, if a single capacitor is used in the input high-pass filter, the -3 dB or cutoff frequency may change when changing gain steps.

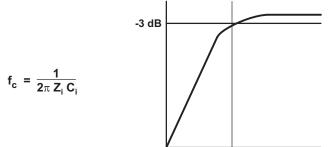


The -3-dB frequency can be calculated using Equation 2. Use the Z_I values given in Table 1.

$$f = \frac{1}{2\pi Z_i C_i}$$
 (2)

INPUT CAPACITOR, C,

In the typical application, an input capacitor (C_I) is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case, C_I and the input impedance of the amplifier (Z_I) form a high-pass filter with the corner frequency determined in Equation 3.



(3)

The value of C_l is important, as it directly affects the bass (low-frequency) performance of the circuit. Consider the example where Z_l is 60 k Ω and the specification calls for a flat bass response down to 20 Hz. Equation 3 is reconfigured as Equation 4.

$$C_i = \frac{1}{2\pi Z_i f_c} \tag{4}$$

In this example, C_l is 0.13 μF ; so, one would likely choose a value of 0.15 μF as this value is commonly used. If the gain is known and is constant, use Z_l from Table 1 to calculate C_l . A further consideration for this capacitor is the leakage path from the input source through the input network (C_l) and the feedback network to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the dc level there is held at 3 V, which is likely higher than the source dc level. Note that it is important to confirm the capacitor polarity in the application. Additionally, lead-free solder can create dc offset voltages and it is important to ensure that boards are cleaned properly.

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NSTRUMENTS

POWER SUPPLY DECOUPLING, Co

The TPA3117D2 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure that the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. Optimum decoupling is achieved by using a network of capacitors of different types that target specific types of noise on the power supply leads. For higher frequency transients due to parasitic circuit elements such as bond wire and copper trace inductances as well as lead frame capacitance, a good quality low equivalent-series-resistance (ESR) ceramic capacitor of value between 220 pF and 1000 pF works well. This capacitor should be placed as close to the device PVCC pins and system ground (either PGND pins or PowerPad) as possible. For mid-frequency noise due to filter resonances or PWM switching transients as well as digital hash on the line, another good quality capacitor typically 0.1 µF to 1 µF placed as close as possible to the device PVCC leads works best For filtering lower frequency noise signals, a larger aluminum electrolytic capacitor of 220 µF or greater placed near the audio power amplifier is recommended. The 220 µF capacitor also serves as a local storage capacitor for supplying current during large signal transients on the amplifier outputs. The PVCC terminals provide the power to the output transistors, so a 220 µF or larger capacitor should be placed on each PVCC terminal. A 10 µF capacitor on the AVCC terminal is adequate. Also, a small decoupling resistor between AVCC and PVCC can be used to keep high frequency class D noise from entering the linear input amplifiers.

BSN and BSP CAPACITORS

The full H-bridge output stages use only NMOS transistors. Therefore, they require bootstrap capacitors for the high side of each output to turn on correctly. A 0.22 µF ceramic capacitor, rated for at least 25 V, must be connected from each output to its corresponding bootstrap input. Specifically, one 0.22 µF capacitor must be connected from OUTPx to BSPx, and one 0.22 µF capacitor must be connected from OUTNx to BSNx. (See the application circuit diagram in Figure 1.)

The bootstrap capacitors connected between the BSxx pins and corresponding output function as a floating power supply for the high-side N-channel power MOSFET gate drive circuitry. During each high-side switching cycle, the bootstrap capacitors hold the gate-to-source voltage high enough to keep the high-side MOSFETs turned on.

DIFFERENTIAL INPUTS

The differential input stage of the amplifier cancels any noise that appears on both input lines of the channel. To use the TPA3117D2 with a differential source, connect the positive lead of the audio source to the INP input and the negative lead from the audio source to the INN input. To use the TPA3117D2 with a single-ended source, ac ground the INP or INN input through a capacitor equal in value to the input capacitor on INN or INP and apply the audio source to either input. In a single-ended input application, the unused input should be ac grounded at the audio source instead of at the device input for best noise performance. For good transient performance, the impedance seen at each of the two differential inputs should be the same.

The impedance seen at the inputs should be limited to an RC time constant of 1 ms or less if possible. This is to allow the input dc blocking capacitors to become completely charged during the 14 ms power-up time. If the input capacitors are not allowed to completely charge, there will be some additional sensitivity to component matching which can result in pop if the input components are not well matched.

USING LOW-ESR CAPACITORS

Low-ESR capacitors are recommended throughout this application section. A real (as opposed to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance, the more the real capacitor behaves like an ideal capacitor.



PRINTED-CIRCUIT BOARD (PCB) LAYOUT

The TPA3117D2 can be used with a small, inexpensive ferrite bead output filter for most applications. However, since the Class-D switching edges are fast, it is necessary to take care when planning the layout of the printed circuit board. The following suggestions will help to meet EMC requirements.

- Decoupling capacitors—The high-frequency decoupling capacitors should be placed as close to the PVCC and AVCC terminals as possible. Large (220 µF or greater) bulk power supply decoupling capacitors should be placed near the TPA3117D2 on the PVCCL and PVCCR supplies. Local, high-frequency bypass capacitors should be placed as close to the PVCC pins as possible. These caps can be connected to the thermal pad directly for an excellent ground connection. Consider adding a small, good quality low ESR ceramic capacitor between 220 pF and 1000 pF and a larger mid-frequency cap of value between 0.1 µF and 1μF also of good quality to the PVCC connections at each end of the chip.
- Keep the current loop from each of the outputs through the ferrite bead and the small filter cap and back to PGND as small and tight as possible. The size of this current loop determines its effectiveness as an antenna.
- Grounding-The AVCC (pin 4) decoupling capacitor should be grounded to analog ground (AGND). The PVCC decoupling capacitors should connect to PGND. Analog ground and power ground should be connected at the thermal pad, which should be used as a central ground connection or star ground for the TPA3117D2.
- Output filter—The ferrite EMI filter (Figure 39) should be placed as close to the output terminals as possible for the best EMI performance. The LC filter (Figure 37 and Figure 38) should be placed close to the outputs. The capacitors used in both the ferrite and LC filters should be grounded to power ground.
- Thermal Pad—The thermal pad must be soldered to the PCB for proper thermal performance and optimal reliability. For recommended PCB footprints, see figures at the end of this data sheet.

For an example layout, see the TPA3117D2 Evaluation Module (TPA3117D2EVM) User Manual, Both the EVM user manual and the thermal pad application report are available on the TI Web site at http://www.ti.com.

Product Folder Link(s): TPA3117D2

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PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|-----------------|-----------------------|------|-------------------------------|----------------------------|--------------|------------------|
| | . , | ` ' | | | | (4) | (5) | | |
| TPA3117D2RHBR | Active | Production | VQFN (RHB) 32 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |
| TPA3117D2RHBR.A | Active | Production | VQFN (RHB) 32 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |
| TPA3117D2RHBRG4 | Active | Production | VQFN (RHB) 32 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |
| TPA3117D2RHBRG4.A | Active | Production | VQFN (RHB) 32 | 3000 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |
| TPA3117D2RHBT | Active | Production | VQFN (RHB) 32 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |
| TPA3117D2RHBT.A | Active | Production | VQFN (RHB) 32 | 250 SMALL T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | TPA3117 |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

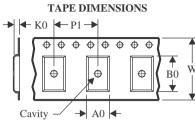
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PACKAGE MATERIALS INFORMATION

www.ti.com 18-Jun-2025

TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPA3117D2RHBR | VQFN | RHB | 32 | 3000 | 330.0 | 12.4 | 5.3 | 5.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPA3117D2RHBRG4 | VQFN | RHB | 32 | 3000 | 330.0 | 12.4 | 5.3 | 5.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPA3117D2RHBT | VQFN | RHB | 32 | 250 | 180.0 | 12.4 | 5.3 | 5.3 | 1.1 | 8.0 | 12.0 | Q2 |

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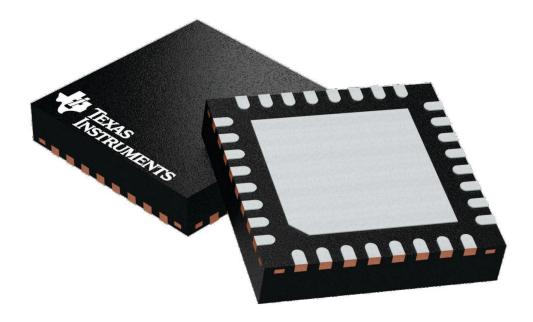


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPA3117D2RHBR | VQFN | RHB | 32 | 3000 | 346.0 | 346.0 | 33.0 |
| TPA3117D2RHBRG4 | VQFN | RHB | 32 | 3000 | 346.0 | 346.0 | 33.0 |
| TPA3117D2RHBT | VQFN | RHB | 32 | 250 | 210.0 | 185.0 | 35.0 |

5 x 5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD



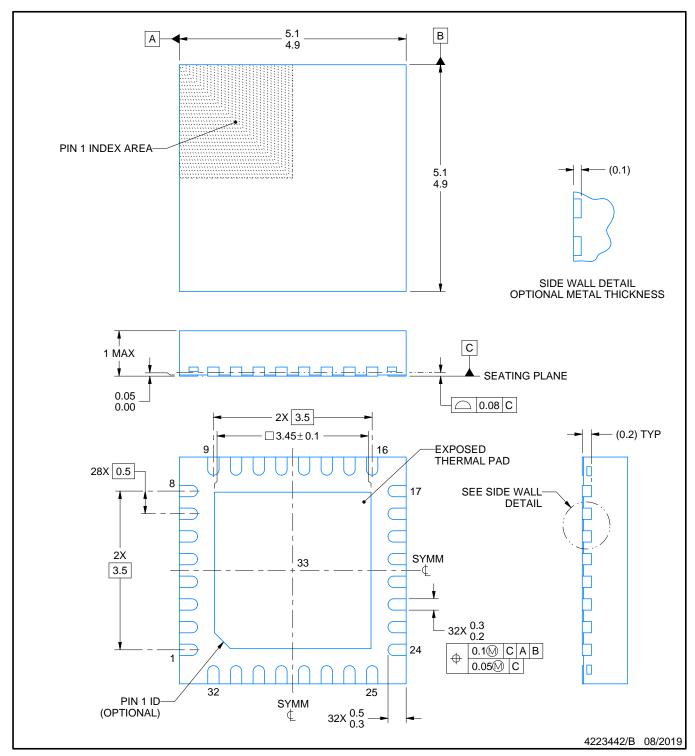
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4224745/A





PLASTIC QUAD FLATPACK - NO LEAD

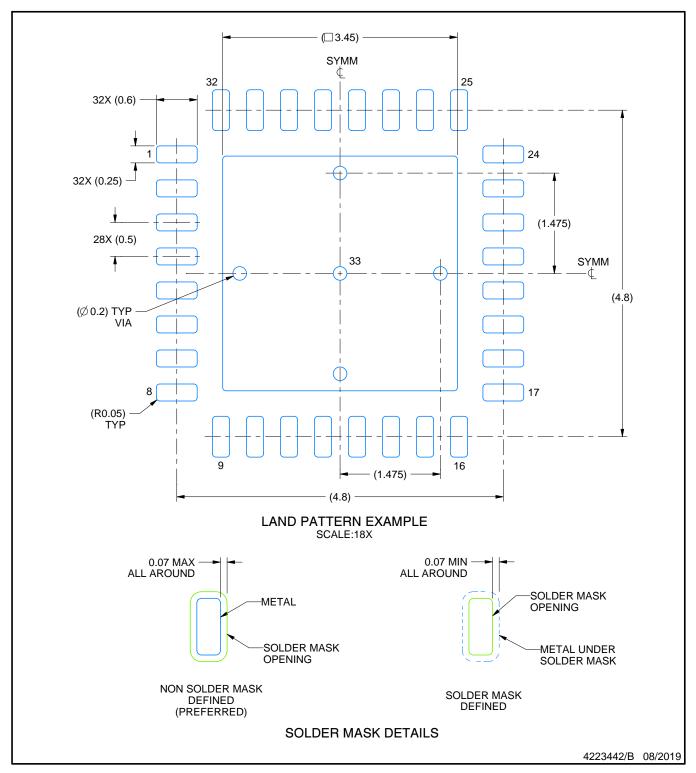


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



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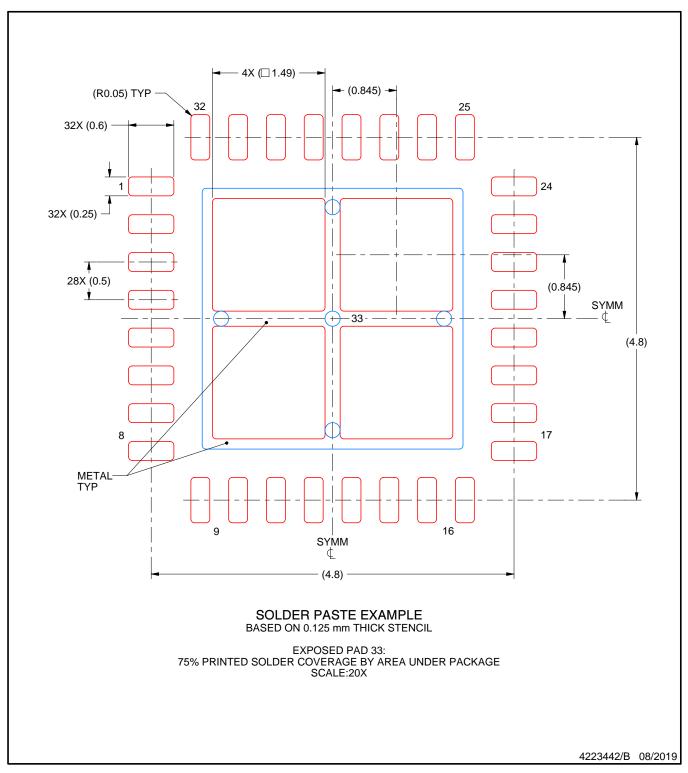


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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